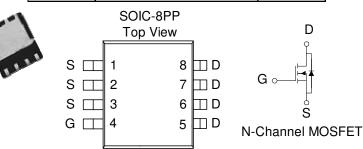
N-Channel 150-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, cellular and cordless telephones.

PRODUCT SUMMARY					
$V_{DS}(V)$ $r_{DS(on)} m(\Omega)$ $I_D(A)$					
150	$220 @ V_{GS} = 10V$	3.9			
	$230 @ V_{GS} = 5.5V$	3.8			

- $\begin{tabular}{ll} \bullet & Low \ r_{DS(on)} \ provides \ higher \ efficiency \ and \\ extends \ battery \ life \end{tabular}$
- Low thermal impedance copper leadframe SOIC-8PP saves board space
- Fast switching speed
- High performance trench technology



ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C UNLESS OTHERWISE NOTED)						
Parameter			Maximum	Units		
Drain-Source Voltage			150	V		
Gate-Source Voltage			20	٧		
Continuous Drain Current ^a	$T_A=25^{\circ}C$	<u> </u>]τ_	3.9			
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	5	A		
Pulsed Drain Current ^b			20			
Continuous Source Current (Diode Conduction) ^a			2.3	A		
D	$T_A=25^{\circ}C$	D_	5.0	W		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	r _D	3.2	VV		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximm	Units	
a	$t \Leftarrow 10 \sec$	D	25	°C/W	
Maximum Junction-to-Ambient ^a	Steady State	$R_{\theta JA}$	65	°C/W	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Analog Power AM7496N

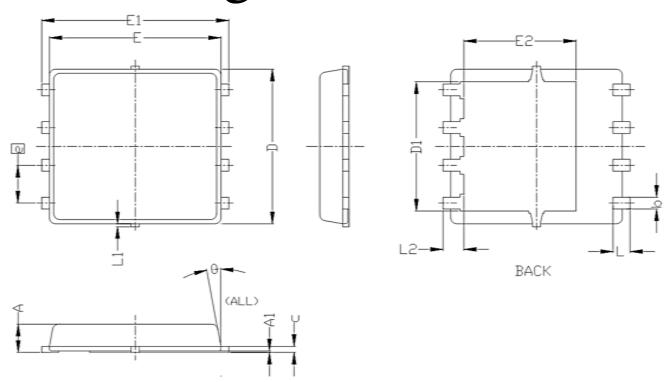
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Parameter	Cymhal	Took Conditions	Limits			Unit	
Parameter	Symbol	Test Conditions	Min	Тур	Max	UIII	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			5	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			A	
Drain-Source On-Resistance ^A	r	$V_{GS} = 10 \text{ V}, I_{D} = 1 \text{ A}$			220	mΩ	
Diani-Source Oil-Resistance	r _{DS(on)}	$V_{GS} = 5.5 \text{ V}, I_D = 1 \text{ A}$			230	11122	
Forward Tranconductance ^A	${f g}_{ m fs}$	$V_{DS} = 15 \text{ V}, I_{D} = 1 \text{ A}$		40		S	
Diode Forward Voltage	V_{SD}	$I_S = 1 A, V_{GS} = 0 V$		0.7		V	
Dynamic ^b							
Total Gate Charge	Q_g	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		10			
Gate-Source Charge	Q_{gs}	$V_{DS} = 13 \text{ V}, V_{GS} = 4.3 \text{ V},$ $I_{D} = 1 \text{ A}$		4		nC	
Gate-Drain Charge	Q_{gd}	ID - 1 A		4			
Turn-On Delay Time	t _{d(on)}			10			
Rise Time	t _r	$V_{DD}=15$ V, $R_L=6~\Omega$, ID = 1 A,		8		nS	
Turn-Off Delay Time	$t_{d(off)}$	VGEN = 10 V		50		110	
Fall-Time	$t_{\rm f}$			50			

Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information



esa mor e	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES			
SYMBOLS	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.85	0. 95	1.00	0.033	0.037	0.039	
Al	0.00		0.05	0.000		0.002	
b	0.30	0.40	0.50	0.012	0.016	0.020	
С	0. 15	0.20	0. 25	0.006	0.008	0.010	
D	5. 20 BSC			0. 205 BSC			
D1	4. 35 BSC		0. 171 BSC				
E	5, 55 BSC			0, 219 BSC			
E1	6. 05 BSC		0. 238 BSC				
E2	3. 62 BSC			0. 143 BSC			
e	1. 27 BSC			0. 050 BSC			
L	0.45	0.55	0.65	0.018	0.022	0.026	
L1	0		0. 15	0		0.006	
L2	0.68 REF			0. 027 REF			
θ	0°		10°	0°		10°	